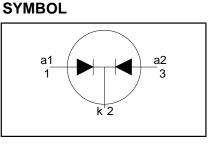
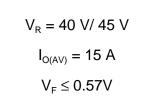
# PBYR1545CTF, PBYR1545CTX series

### FEATURES

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Isolated mounting tab



## QUICK REFERENCE DATA



### **GENERAL DESCRIPTION**

Dual, common cathode schottky rectifier diodes in a plastic envelope with electrically isolated mounting tab. Intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

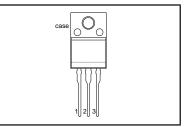
The PBYR1545CTF series is supplied in the SOT186 package. The PBYR1545CTX series is supplied in the SOT186A package.

### PINNING

PIN	DESCRIPTION
1	anode 1 (a)
2	cathode (k)
3	anode 2 (a)
tab	isolated



### SOT186A



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MA	Х.	UNIT
		PBYR15 PBYR15		40CTF 40CTX	45CTF 45CTX	
V <sub>RRM</sub>	Peak repetitive reverse voltage		-	40	45	V
$V_{\text{RWM}}$	Working peak reverse voltage		-	40	45	V
V <sub>R</sub>	Continuous reverse voltage	T <sub>hs</sub> ≤ 89 °C	-	40	45	V
I <sub>O(AV)</sub>	Average rectified output current (both diodes conducting)	square wave; $\delta = 0.5$ ; $T_{hs} \leq 93 \degree C$	-	15	5	A
I <sub>FRM</sub>	Repetitive peak forward current per diode	square wave; $\delta = 0.5$ ; T <sub>hs</sub> $\leq$ 93 °C	-	1	5	A
I <sub>FSM</sub>	Non-repetitive peak forward current per diode	t = 10 ms t = 8.3 ms sinusoidal; T <sub>j</sub> = 125 °C prior to surge; with reapplied $V_{RRM(max)}$	-	10 11		AA
I <sub>RRM</sub>	Peak repetitive reverse surge current per diode	pulse width and repetition rate limited by T <sub>imax</sub>	-	1		A
$\mathbf{T}_{j}$	Operating junction temperature		-	15	0	°C
T <sub>stg</sub>	Storage temperature		- 65	17	5	°C

# PBYR1545CTF, PBYR1545CTX series

# **ISOLATION LIMITING VALUE & CHARACTERISTIC**

 $T_{hs} = 25$  °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>isol</sub>	Peak isolation voltage from all terminals to external heatsink	SOT186 package; R.H. $\leq$ 65%; clean and dustfree	-	-	1500	V
V <sub>isol</sub>	R.M.S. isolation voltage from all terminals to external heatsink	SOT186A package; f = 50-60 Hz; sinusoidal waveform; R.H. $\leq$ 65%; clean and dustfree	-	-	2500	V
C <sub>isol</sub>	Capacitance from pin 2 to external heatsink	f = 1 MHz	-	10	-	pF

### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-hs</sub>	Thermal resistance junction	per diode	-	-	6	K/W
	to heatsink	both diodes (with heatsink compound)	-	-	5.2	K/W
R <sub>th j-a</sub>	Thermal resistance junction to ambient	in free air	-	55	-	K/W

### **ELECTRICAL CHARACTERISTICS**

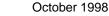
 $T_i = 25$  °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 7.5 A; T <sub>i</sub> = 125°C	-	0.44	0.57	V
· ·		I <sub>F</sub> = 15 A; T <sub>i</sub> = 125°C	-	0.63	0.72	V
		$I_{\rm F} = 15  {\rm A}^{-1}$	-	0.62	0.84	V
I <sub>R</sub>	Reverse current	$\dot{V}_{R} = V_{RWM}$	-	0.22	1	mA
		V <sub>R</sub> = V <sub>RWM</sub> ; T <sub>j</sub> = 100°C V <sub>R</sub> = 5 V; f = 1 MHz, T <sub>i</sub> = 25°C to 125°C	-	18	25	mA
C <sub>d</sub>	Junction capacitance	$V_{R}^{A} = 5 \text{ V}; \text{ f} = 1 \text{ MHz}, \text{ T}_{j} = 25 \text{ °C to } 125 \text{ °C}$	-	270	-	pF

PBYR1545CTF, PBYR1545CTX series

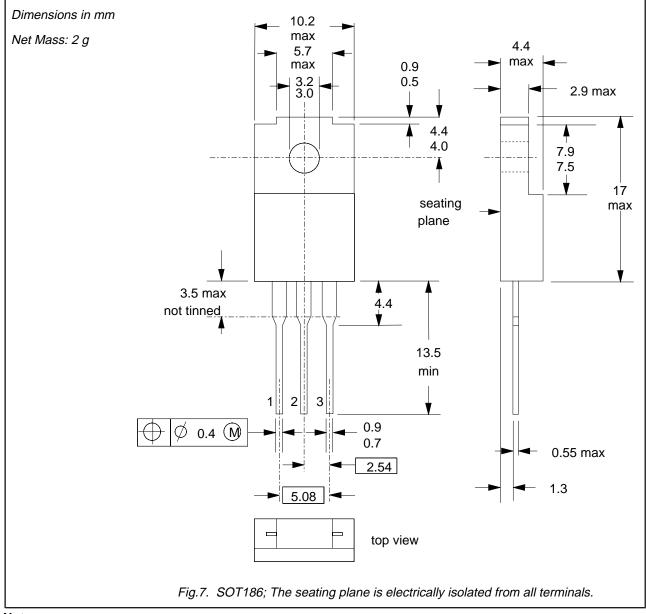
# Rectifier diodes Schottky barrier

#### Ths(max) (C) Forward dissipation, PF (W) Reverse current, IR (mA) 8 100 $V_0 = 0.42 V$ Rs = 0.02 Obr 108 7 D = 1.0 125 C 6 114 10 0.5 100 C 120 5 0.2 4 126 \_75 C 1 3 132 50 C - to п 2 138 0.1 Tj = 25 C 144 1 0 150 0.01 4 6 8 Average forward current, IF(AV) (A) 0 2 10 12 25 Reverse voltage, VR (V) 0 50 Maximum forward dissipation $P_F = f(I_{F(AV)})$ per diode; square current waveform where Fig.4. Typical reverse leakage current per diode; Fig.1. $I_R = f(V_R)$ ; parameter $T_i$ $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}.$ Ths(max) / C 102 Forward dissipation, PF (W) Cd / pF 8 1000 Vo = 0 42 V Rs = 0 02 Ohn 108 7 114 6 a = 1.57 5 120 2.8 126 4 100 3 132 2 138 144 1 10 150 0 10 100 2 3 4 5 6 Average forward current, IF(AV) (A) 0 7 8 VR / V Fig.2. Maximum forward dissipation $P_F = f(I_{F(AV)})$ per diode; sinusoidal current waveform where a = formFig.5. Typical junction capacitance per diode; $C_d = f(V_R)$ ; f = 1 MHz; $T_j = 25^{\circ}C$ to $125^{\circ}C$ . factor = $I_{F(RMS)} / I_{F(AV)}$ . Transient thermal impedance, Zth j-hs (K/W) Forward current, IF (A) 10 50 Tj = 25 C → Tj = 125 C 40 30 typ 20 0.1 D = ≥max 10 : \_\_+| ⊤ |+\_\_ ' 0.01 L\_\_\_ 1us 0 L. 0 10us 100us 1ms 10ms 100ms 1s 10s 0.4 0.6 0.8 1 Forward voltage, VF (V) 0.2 1.2 1.4 pulse width, tp (s) Fig.3. Typical and maximum forward characteristic Fig.6. Transient thermal impedance per diode; $Z_{thj\cdot hs} = f(t_p).$ $I_F = f(V_F)$ ; parameter $T_i$



# PBYR1545CTF, PBYR1545CTX series

### **MECHANICAL DATA**

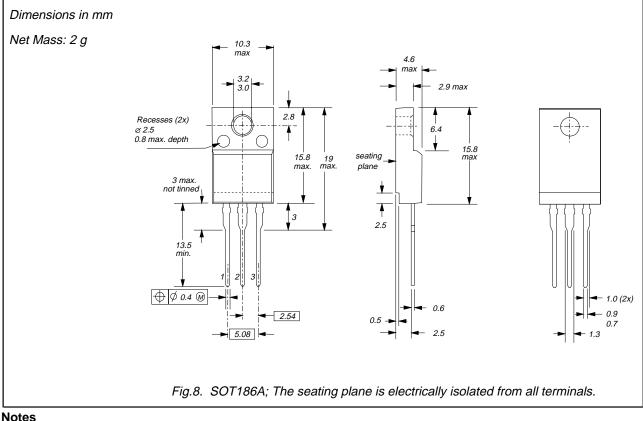


### Notes

Refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

# PBYR1545CTF, PBYR1545CTX series

## **MECHANICAL DATA**



### Notes

Refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

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### DEFINITIONS

Data sheet status				
Objective specification This data sheet contains target or goal specifications for product development.				
Preliminary specification This data sheet contains preliminary data; supplementary data may be published la				
Product specification	This data sheet contains final product specifications.			
Limiting values				
or more of the limiting val operation of the device at	in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one ues may cause permanent damage to the device. These are stress ratings only and these or at any other conditions above those given in the Characteristics sections of applied. Exposure to limiting values for extended periods may affect device reliability.			
Application information				
Where application inform	ation is given, it is advisory and does not form part of the specification.			
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